NSN 5961-01-141-1767

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Inclosure Material:

Plastic

Overall Length:

Between 0.380 inches and 0.420 inches

Overall Height:

Between 0.140 inches and 0.190 inches

Overall Width:

Between 0.330 inches and 0.355 inches

End Application:

C141fltsimref 82932

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-220b

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

120.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

10.00 microamperes zero-gate-voltage source current preset

Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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